Amendments to the Claims:

Following is a listing of all claims in the present application, which listing supersedes all previously presented claims:

Listing of Claims:

- 1-19. (Cancelled)
- 20. (Original) A MEMS device, comprising:
- a fixing part fixed to a substrate;
- a driving part connected to the fixing part by a connecting part and floating over the substrate;

an electrode part for driving the driving part; and contact parts selectively switchable with the driving part, wherein the electrode part and the contact parts are planarized on the substrate.

- 21. (Currently Amended) The MEMS device as claimed in claim 20, wherein the electrode part includes an electrode and an insulation layer covering the electrode to electrically isolate the driving part and the electrode, the electrode being embedded in the insulation layer.
- 22. (Original) The MEMS device as claimed in claim 20, further comprising: an anchor inserted between the fixing part and the substrate for fixing the fixing part on the substrate; and

sidewalls on at least a portion of side surfaces of the anchor.

- 23. (Original) The MEMS device as claimed in claim 20, wherein the sidewalls are substantially formed over the entire portion remaining except for a portion corresponding to a connection part connecting the fixing part and the driving part.
- 24. (Original) The MEMS device as claimed in claim 20, wherein a width of the connection part is narrower than that of the fixing part.

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- 25. (Original) The MEMS device as claimed in claim 22, wherein the sidewalls, fixing part, and driving part are integrally formed in one body.
- 26. (Original) The MEMS device as claimed in claim 25, wherein the sidewalls are in contact with the substrate.
- 27. (New) The MEMS device as claimed in claim 21, wherein the electrode is embedded in the insulation layer.
- 28. (New) The MEMS device as claimed in claim 27, wherein the insulating layer is integral in a single layer.
- 29. (New-Withdrawn) The MEMS device as claimed in claim 27, wherein the insulating layer includes a first insulating layer around sides of the electrode part and a second insulating layer on top of the electrode part.
- 30. (New) The MEMS device as claimed in claim 22, further comprising a support structure adjacent a sidewall and between the anchor and a contact part under the anchor.
- 31. (New) The MEMS device as claimed in claim 30, wherein the support structure is at least one of aluminum, copper, oxide and nickel.